4N32, 4N33

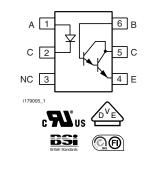


www.vishay.com

Vishay Semiconductors

Optocoupler, Photodarlington Output, High Gain, With Base Connection





DESCRIPTION

The 4N32 and 4N33 are optically coupled isolators with a gallium arsenide infrared LED and a solicon photodarlington sensor.

Switching can be achieved while maintaining a high degree of isolation between driving and load circuits.

These optocouplers can be used to replace reed and mercury relays with advantages of long life, high speed switching and elimination of magnetic fields.

FEATURES

- Very high current transfer ratio, 500 % min.
- High isolation resistance, 10¹¹ Ω typical
- Standard plastic DIP package
- Material categorization:



RoHS

COMPLIANT

for definitions of compliance please see www.vishay.com/doc?99912

AGENCY APPROVALS

- UL1577, file no. E52744 system code H
- DIN EN 60747-5-2 (VDE 0884) / DIN EN 60747-5-5 (pending), available with option 1
- BSI IEC 60950; IEC 60065
- FIMKO

| ORDERING INFORMATION | | | |
|----------------------------------|--|---------------------------|--|
| 4 N 3 # - | X 0 # # T PACKAGE OPTION TAPE A REEL | | |
| AGENCY CERTIFIED/PACKAGE CTR (%) | | (%) | |
| UL, BSI, FIMKO | ≥ 500 ≥ 500 | | |
| DIP-6 | 4N32 4N33 | | |
| DIP-6, 400 mil, option 6 | 4N32-X006 | - | |
| SMD-6, option 7 | 4N32-X007T ⁽¹⁾ | 4N33-X007T ⁽¹⁾ | |
| SMD-6, option 9 | 4N32-X009T ⁽¹⁾ | 4N33-X009T ⁽¹⁾ | |
| VDE, UL, BSI, FIMKO | ≥ 500 | ≥ 500 | |
| DIP-6 | 4N32-X001 | 4N33-X001 | |
| SMD-6, option 7 | 4N32-X017T | 4N33-X017T ⁽¹⁾ | |

Notes

· Additional options may be possible, please contact sales office

⁽¹⁾ Also available in tubes, do not put T on the end



www.vishay.com

4N32, 4N33

Vishay Semiconductors

| ABSOLUTE MAXIMUM RATIN | | - | | |
|---|--|-------------------|--------------------|------------------|
| PARAMETER | TEST CONDITION | SYMBOL | VALUE | UNIT |
| INPUT | | | | |
| Reverse voltage | | V _R | 3 | V |
| Forward current | | ١ _F | 60 | mA |
| Power dissipation | | P _{diss} | 100 | mW |
| Derate linearly | From 55 °C | | 1.33 | mW/°C |
| OUTPUT | | | | |
| Collector emitter breakdown voltage | | BV _{CEO} | 30 | V |
| Emitter base breakdown voltage | | BV _{EBO} | 8 | V |
| Collector base breakdown voltage | | BV _{CBO} | 50 | V |
| Emitter collector breakdown voltage | | BV _{ECO} | 5 | V |
| Collector (load) current | | Ι _C | 100 | mA |
| Power dissipation | | P _{diss} | 150 | mW |
| Derate linearly | | | 2 | mW/°C |
| COUPLER | | | | |
| Total dissipation | | P _{tot} | 250 | mW |
| Derate linearly | | | 3.3 | mW/°C |
| Isolation test voltage (between emitter | 1 s | V _{ISO} | 5300 | V _{RMS} |
| Leakage path | | | 7 | mm min. |
| Air path | | | 7 | mm min. |
| Indiction registered | $V_{IO} = 500 \text{ V}, \text{ T}_{amb} = 25 ^{\circ}\text{C}$ | R _{IO} | ≥ 10 ¹² | Ω |
| Isolation resistance | $V_{IO} = 500 \text{ V}, \text{ T}_{amb} = 100 ^{\circ}\text{C}$ | R _{IO} | ≥ 10 ¹¹ | Ω |
| Storage temperature | | T _{stg} | -55 to +150 | °C |
| Operating temperature | | T _{amb} | -55 to +100 | °C |
| Lead soldering time ⁽¹⁾ | at 260 °C | | 10 | S |

Notes

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

(1) Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

| PARAMETER | TEST CONDITION | SYMBOL | MIN. | TYP. | MAX. | UNIT |
|--|--|--------------------|------|------|------|------|
| INPUT | | | | | | |
| Forward voltage | I _F = 50 mA | V _F | - | 1.25 | 1.5 | V |
| Reverse current | V _R = 3 V | I _R | - | 0.1 | 100 | μA |
| Capacitance | V _R = 0 V | Co | - | 25 | | pF |
| OUTPUT | | | | | • | |
| Collector emitter breakdown voltage ⁽¹⁾ | $I_{C} = 100 \ \mu A, \ I_{F} = 0$ | BV _{CEO} | 30 | - | - | V |
| Collector base breakdown voltage (1) | $I_{C} = 100 \ \mu A, \ I_{F} = 0$ | BV _{CBO} | 50 | - | - | V |
| Emitter base breakdown voltage (1) | I _C = 100 μA, I _F = 0 | BV _{EBO} | 8 | - | - | V |
| Emitter collector breakdown voltage (1) | $I_{C} = 100 \ \mu A, \ I_{F} = 0$ | BV _{ECO} | 5 | 10 | - | V |
| Collector emitter leakage current | $V_{CE} = 10 \text{ V}, \text{ I}_{F} = 0$ | I _{CEO} | - | 1 | 100 | nA |
| | $I_{C} = 0.5 \text{ mA}, V_{CE} = 5 \text{ V}$ | h _{FE} | 13 | - | - | |
| COUPLER | | | | • | • | • |
| Collector emitter saturation voltage | | V _{CEsat} | - | 1 | - | V |
| Coupling capacitance | | | - | 1.5 | - | pF |

Notes

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements

ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

⁽¹⁾ Indicates JEDEC[®] registered values



www.vishay.com

Vishay Semiconductors

4N32, 4N33

| CURRENT TRANSFER RATIO | | | | | | |
|------------------------|--|--------|------|------|------|------|
| PARAMETER | TEST CONDITION | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| Current transfer ratio | $V_{CE} = 10 \text{ V}, I_F = 10 \text{ mA}$ | CTR | 500 | - | - | % |

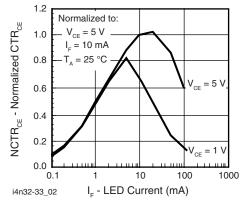
| SWITCHING CHARACTERISTICS | | | | | | |
|---------------------------|--|------------------|------|------|------|------|
| PARAMETER | TEST CONDITION | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| Turn-on time | $V_{CC} = 10 \text{ V}, \text{ I}_{C} = 50 \text{ mA}$ | t _{on} | - | - | 5 | μs |
| Turn-off time | $\rm I_F$ = 200 mA, $\rm R_L$ = 180 Ω | t _{off} | - | - | 100 | μs |

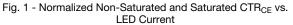
| PARAMETER | TEST CONDITION | SYMBOL | MIN. | TYP. | MAX. | UNIT |
|---|------------------------|--------|------|---------------|------|------|
| Climatic classification (according to IEC 68 part 1) | | | - | 55 / 100 / 21 | - | |
| Comparative tracking index | | CTI | 175 | - | 399 | |
| V _{IOTM} | | | 8000 | - | - | V |
| V _{IORM} | | | 890 | - | - | V |
| P _{SO} | | | - | - | 700 | mW |
| I _{SI} | | | - | - | 400 | mA |
| T _{SI} | | | - | - | 175 | °C |
| Creepage distance | Standard DIP-6 | | 7 | - | - | mm |
| Clearance distance | Standard DIP-6 | | 7 | - | - | mm |
| Creepage distance | 400 mil DIP-6 | | 8 | - | - | mm |
| Clearance distance | 400 mil DIP-6 | | 8 | - | - | mm |
| Insulation thickness, reinforced rated | per IEC 60950 2.10.5.1 | | 0.4 | - | - | mm |

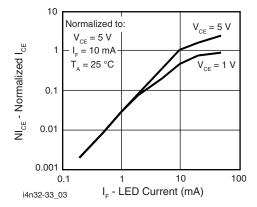
Note

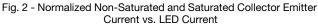
As per IEC 60747-5-2, § 7.4.3.8.1, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with
the safety ratings shall be ensured by means of protective circuits

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)









3



www.vishay.com

4N32, 4N33

Vishay Semiconductors

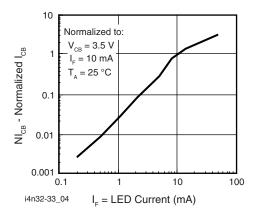


Fig. 3 - Normalized Collector Base Photocurrent vs. LED Current

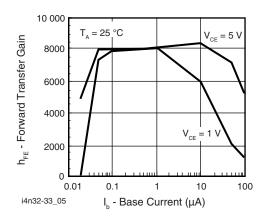


Fig. 4 - Non-Saturated and Saturated h_{FE} vs. Base Current

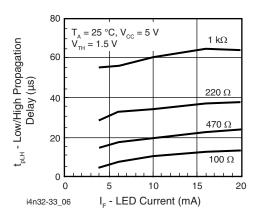


Fig. 5 - Low to High Propagation Delay vs. Collector Load Resistance and LED Current

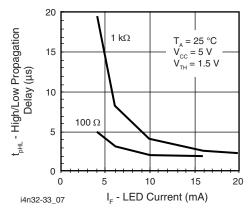


Fig. 6 - High to Low Propagation Delay vs. Collector Load Resistance and LED Current

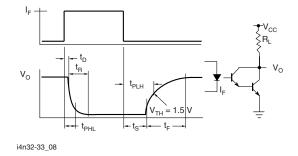


Fig. 7 - Switching Waveform and Switching Schematic

For technical questions, contact: <u>optocoupleranswers@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

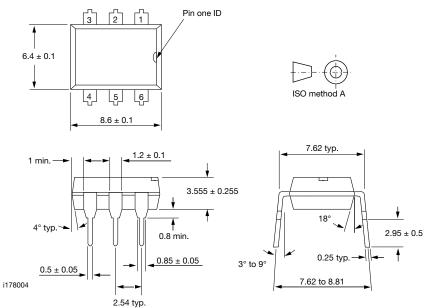


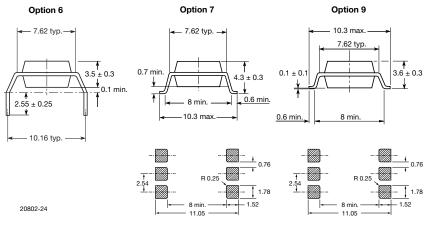
www.vishay.com

4N32, 4N33 Vishay Semiconductors

PACKAGE DIMENSIONS in millimeters

DIP-6 Package Dimensions





PACKAGE MARKING



Notes

- Example marking for 4N32-X017T
- Only options 1, and 7 reflected in the package marking
- The VDE logo is only marked on option 1 parts
- Tape and reel suffix (T) is not part of the package marking

5



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.